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(E)-N-[4-(Methylsulfonyl)benzylidene]-aniline

Shao-Song Qian* and Tao Liu

School of Life Sciences, Shandong University of Technology, Zibo 255049, People's Republic of China

Correspondence e-mail: njuqss@yahoo.com.cn

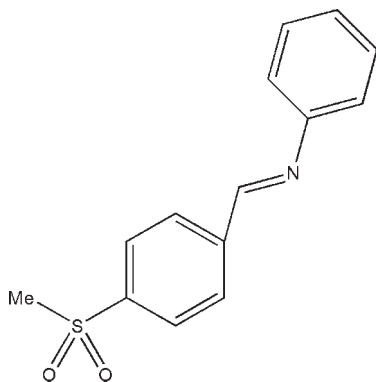
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Key indicators: single-crystal X-ray study; $T = 293$ K; mean $\sigma(\text{C}-\text{C}) = 0.005$ Å; R factor = 0.052; wR factor = 0.138; data-to-parameter ratio = 14.1.

The molecule of the title compound, $\text{C}_{14}\text{H}_{13}\text{NO}_2\text{S}$, displays a *trans* configuration with respect to the $\text{C}=\text{N}$ double bond. The dihedral angle between the two aromatic ring planes is 62.07 (18)°.

Related literature

For a related structure, see: Qian & Cui (2009). For comparative bond lengths, see: Allen *et al.* (1987).



Experimental

Crystal data

$\text{C}_{14}\text{H}_{13}\text{NO}_2\text{S}$
 $M_r = 259.31$
 Monoclinic, $P2_1/c$
 $a = 8.2070$ (16) Å
 $b = 5.7750$ (12) Å
 $c = 26.945$ (5) Å
 $\beta = 94.72$ (3)°

$V = 1272.7$ (4) Å³
 $Z = 4$
 Mo $K\alpha$ radiation
 $\mu = 0.25$ mm⁻¹
 $T = 293$ K
 $0.30 \times 0.20 \times 0.10$ mm

Data collection

Enraf–Nonius CAD-4
 diffractometer
 Absorption correction: multi-scan
 (SADABS; Sheldrick, 1996)
 $T_{\min} = 0.930$, $T_{\max} = 0.976$
 2462 measured reflections

2292 independent reflections
 1542 reflections with $I > 2\sigma(I)$
 $R_{\text{int}} = 0.053$
 3 standard reflections
 every 200 reflections
 intensity decay: 1%

Refinement

$R[F^2 > 2\sigma(F^2)] = 0.052$
 $wR(F^2) = 0.138$
 $S = 1.03$
 2292 reflections

163 parameters
 H-atom parameters constrained
 $\Delta\rho_{\text{max}} = 0.29$ e Å⁻³
 $\Delta\rho_{\text{min}} = -0.34$ e Å⁻³

Data collection: *CAD-4 Software* (Enraf–Nonius, 1989); cell refinement: *CAD-4 Software*; data reduction: *XCAD4* (Harms & Wocadlo, 1995); program(s) used to solve structure: *SHELXS97* (Sheldrick, 2008); program(s) used to refine structure: *SHELXL97* (Sheldrick, 2008); molecular graphics: *SHELXTL* (Sheldrick, 2008); software used to prepare material for publication: *SHELXTL*.

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Supplementary data and figures for this paper are available from the IUCr electronic archives (Reference: RZ2398).

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supplementary materials

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(*E*)-*N*-[4-(Methylsulfonyl)benzylidene]aniline

S.-S. Qian and T. Liu

Comment

Schiff base compounds have been of great of interest for many years, and act as important precursors for coordination chemistry related to catalysis and enzymatic reactions, magnetism and molecular architectures. As an extension of work on the structural characterization of Schiff base compounds, the crystal structure of the title compound is reported here.

In the title compound (Fig. 1), all bond lengths are within normal ranges (Allen *et al.*, 1987) and comparable to the values observed in a closely related compound (Qian *et al.*, 2009). The molecule displays a *trans*-configuration with respect to the C=N double bond. The dihedral angle between two aromatic ring planes is 62.07 (18)°. The crystal packing is stabilized only by van der Waals interactions.

Experimental

4-(Methylsulfonyl)benzaldehyde (0.184 g) and aniline (0.093 g) were dissolved in acetonitrile (20 ml). The mixture was stirred at room temperature for 10 min to give a clear yellow solution. After keeping the solution in air for 7 d, yellow block-shaped crystals suitable for X-ray analysis were formed at the bottom of the vessel on slow evaporation of the solvent.

Refinement

All H atoms were placed in geometrical positions and constrained to ride on their parent atoms, with C—H = 0.93–0.96 Å, and with $U_{\text{iso}}(\text{H}) = 1.2 U_{\text{eq}}(\text{C})$ or $1.5 U_{\text{eq}}(\text{C})$ for methyl H atoms.

Figures

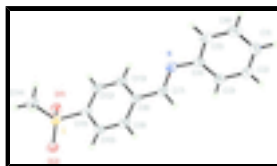


Fig. 1. The structure of the title compound, showing the atom-labelling scheme. Displacement ellipsoids are drawn at the 35% probability level.

(*E*)-*N*-[4-(Methylsulfonyl)benzylidene]aniline

Crystal data

C₁₄H₁₃NO₂S

$M_r = 259.31$

Monoclinic, $P2_1/c$

Hall symbol: -P 2ybc

$a = 8.2070$ (16) Å

$F(000) = 544$

$D_x = 1.353$ Mg m⁻³

Mo $K\alpha$ radiation, $\lambda = 0.71073$ Å

Cell parameters from 25 reflections

$\theta = 9\text{--}13^\circ$

supplementary materials

$b = 5.7750 (12) \text{ \AA}$	$\mu = 0.25 \text{ mm}^{-1}$
$c = 26.945 (5) \text{ \AA}$	$T = 293 \text{ K}$
$\beta = 94.72 (3)^\circ$	Block, yellow
$V = 1272.7 (4) \text{ \AA}^3$	$0.30 \times 0.20 \times 0.10 \text{ mm}$
$Z = 4$	

Data collection

Enraf–Nonius CAD-4 diffractometer	1542 reflections with $I > 2\sigma(I)$
Radiation source: fine-focus sealed tube	$R_{\text{int}} = 0.053$
graphite	$\theta_{\text{max}} = 25.3^\circ$, $\theta_{\text{min}} = 1.5^\circ$
$\omega/2\theta$ scans	$h = 0 \rightarrow 9$
Absorption correction: multi-scan (SADABS; Sheldrick, 1996)	$k = 0 \rightarrow 6$
$T_{\text{min}} = 0.930$, $T_{\text{max}} = 0.976$	$l = -32 \rightarrow 32$
2462 measured reflections	3 standard reflections every 200 reflections
2292 independent reflections	intensity decay: 1%

Refinement

Refinement on F^2	Primary atom site location: structure-invariant direct methods
Least-squares matrix: full	Secondary atom site location: difference Fourier map
$R[F^2 > 2\sigma(F^2)] = 0.052$	Hydrogen site location: inferred from neighbouring sites
$wR(F^2) = 0.138$	H-atom parameters constrained
$S = 1.03$	$w = 1/[\sigma^2(F_o^2) + (0.0501P)^2 + 1.018P]$
2292 reflections	where $P = (F_o^2 + 2F_c^2)/3$
163 parameters	$(\Delta/\sigma)_{\text{max}} < 0.001$
0 restraints	$\Delta\rho_{\text{max}} = 0.29 \text{ e \AA}^{-3}$
	$\Delta\rho_{\text{min}} = -0.34 \text{ e \AA}^{-3}$

Special details

Geometry. All esds (except the esd in the dihedral angle between two l.s. planes) are estimated using the full covariance matrix. The cell esds are taken into account individually in the estimation of esds in distances, angles and torsion angles; correlations between esds in cell parameters are only used when they are defined by crystal symmetry. An approximate (isotropic) treatment of cell esds is used for estimating esds involving l.s. planes.

Refinement. Refinement of F^2 against ALL reflections. The weighted R-factor wR and goodness of fit S are based on F^2 , conventional R-factors R are based on F, with F set to zero for negative F^2 . The threshold expression of $F^2 > 2\sigma(F^2)$ is used only for calculating R-factors(gt) etc. and is not relevant to the choice of reflections for refinement. R-factors based on F^2 are statistically about twice as large as those based on F, and R-factors based on ALL data will be even larger.

Fractional atomic coordinates and isotropic or equivalent isotropic displacement parameters (\AA^2)

x	y	z	$U_{\text{iso}}^*/U_{\text{eq}}$
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S	0.80688 (10)	0.31400 (15)	0.45864 (3)	0.0473 (3)
N	0.1198 (3)	-0.1536 (5)	0.34256 (10)	0.0474 (7)
O1	0.9360 (3)	0.2295 (5)	0.43114 (9)	0.0609 (7)
C1	-0.3341 (4)	-0.2970 (7)	0.26535 (15)	0.0635 (11)
H1B	-0.4331	-0.3326	0.2477	0.076*
O2	0.8001 (3)	0.5582 (4)	0.46914 (11)	0.0680 (8)
C2	-0.2463 (5)	-0.1064 (7)	0.25292 (15)	0.0592 (10)
H2B	-0.2866	-0.0125	0.2267	0.071*
C3	-0.0992 (4)	-0.0518 (6)	0.27874 (13)	0.0488 (9)
H3A	-0.0420	0.0793	0.2701	0.059*
C4	-0.0363 (4)	-0.1919 (6)	0.31746 (12)	0.0426 (8)
C5	-0.1259 (4)	-0.3852 (6)	0.32996 (14)	0.0537 (9)
H5A	-0.0857	-0.4813	0.3558	0.064*
C6	-0.2737 (5)	-0.4344 (7)	0.30415 (16)	0.0632 (11)
H6A	-0.3334	-0.5624	0.3131	0.076*
C7	0.1609 (4)	0.0524 (6)	0.35336 (12)	0.0467 (8)
H7A	0.0855	0.1699	0.3458	0.056*
C8	0.3215 (4)	0.1149 (6)	0.37721 (12)	0.0433 (8)
C9	0.3412 (4)	0.3236 (6)	0.40197 (15)	0.0586 (10)
H9A	0.2534	0.4255	0.4017	0.070*
C10	0.4877 (4)	0.3840 (6)	0.42707 (14)	0.0564 (10)
H10A	0.4982	0.5241	0.4441	0.068*
C11	0.6192 (4)	0.2351 (6)	0.42680 (12)	0.0435 (8)
C12	0.6034 (4)	0.0265 (6)	0.40118 (14)	0.0549 (10)
H12A	0.6925	-0.0726	0.4004	0.066*
C13	0.4555 (4)	-0.0325 (6)	0.37695 (14)	0.0537 (9)
H13A	0.4447	-0.1729	0.3601	0.064*
C14	0.8121 (4)	0.1617 (7)	0.51489 (13)	0.0603 (10)
H14A	0.9119	0.1963	0.5346	0.090*
H14B	0.8065	-0.0015	0.5082	0.090*
H14C	0.7206	0.2067	0.5327	0.090*

Atomic displacement parameters (\AA^2)

	U^{11}	U^{22}	U^{33}	U^{12}	U^{13}	U^{23}
S	0.0448 (5)	0.0432 (5)	0.0537 (6)	0.0085 (4)	0.0032 (4)	0.0064 (4)
N	0.0488 (16)	0.0410 (17)	0.0523 (17)	0.0068 (14)	0.0040 (13)	0.0032 (14)
O1	0.0459 (13)	0.0773 (19)	0.0610 (16)	0.0114 (13)	0.0130 (11)	0.0111 (14)
C1	0.053 (2)	0.066 (3)	0.071 (3)	-0.004 (2)	-0.0011 (19)	-0.007 (2)
O2	0.0654 (16)	0.0407 (14)	0.094 (2)	0.0054 (13)	-0.0148 (15)	-0.0008 (14)
C2	0.058 (2)	0.060 (3)	0.059 (2)	0.010 (2)	-0.0002 (19)	0.007 (2)
C3	0.053 (2)	0.0402 (19)	0.054 (2)	0.0019 (17)	0.0059 (17)	0.0059 (17)
C4	0.0486 (19)	0.0355 (18)	0.0449 (19)	0.0070 (16)	0.0099 (15)	-0.0033 (16)
C5	0.062 (2)	0.040 (2)	0.060 (2)	0.0055 (18)	0.0112 (19)	0.0028 (17)
C6	0.064 (2)	0.047 (2)	0.081 (3)	-0.008 (2)	0.015 (2)	-0.001 (2)
C7	0.050 (2)	0.043 (2)	0.047 (2)	0.0093 (16)	0.0067 (16)	-0.0008 (17)
C8	0.0459 (19)	0.0406 (19)	0.0437 (19)	0.0078 (15)	0.0044 (15)	0.0014 (15)
C9	0.050 (2)	0.045 (2)	0.079 (3)	0.0195 (18)	-0.0019 (19)	-0.008 (2)

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C10	0.052 (2)	0.042 (2)	0.074 (3)	0.0153 (17)	-0.0066 (19)	-0.0130 (19)
C11	0.0469 (18)	0.0373 (19)	0.047 (2)	0.0096 (15)	0.0088 (15)	0.0063 (15)
C12	0.048 (2)	0.044 (2)	0.073 (3)	0.0183 (17)	0.0069 (19)	-0.0034 (19)
C13	0.054 (2)	0.039 (2)	0.068 (2)	0.0087 (17)	0.0065 (18)	-0.0107 (18)
C14	0.061 (2)	0.066 (3)	0.054 (2)	0.018 (2)	0.0050 (18)	0.008 (2)

Geometric parameters (Å, °)

S—O1	1.428 (2)	C6—H6A	0.9300
S—O2	1.440 (3)	C7—C8	1.463 (5)
S—C14	1.750 (4)	C7—H7A	0.9300
S—C11	1.760 (4)	C8—C9	1.381 (5)
N—C7	1.264 (4)	C8—C13	1.391 (4)
N—C4	1.416 (4)	C9—C10	1.375 (5)
C1—C2	1.372 (5)	C9—H9A	0.9300
C1—C6	1.372 (5)	C10—C11	1.380 (4)
C1—H1B	0.9300	C10—H10A	0.9300
C2—C3	1.379 (5)	C11—C12	1.389 (5)
C2—H2B	0.9300	C12—C13	1.373 (5)
C3—C4	1.386 (4)	C12—H12A	0.9300
C3—H3A	0.9300	C13—H13A	0.9300
C4—C5	1.393 (5)	C14—H14A	0.9600
C5—C6	1.377 (5)	C14—H14B	0.9600
C5—H5A	0.9300	C14—H14C	0.9600
O1—S—O2	118.61 (17)	N—C7—H7A	118.4
O1—S—C14	108.15 (16)	C8—C7—H7A	118.4
O2—S—C14	108.70 (19)	C9—C8—C13	118.4 (3)
O1—S—C11	108.39 (15)	C9—C8—C7	119.6 (3)
O2—S—C11	107.63 (15)	C13—C8—C7	122.1 (3)
C14—S—C11	104.47 (17)	C10—C9—C8	121.5 (3)
C7—N—C4	118.1 (3)	C10—C9—H9A	119.3
C2—C1—C6	119.1 (4)	C8—C9—H9A	119.3
C2—C1—H1B	120.5	C9—C10—C11	119.4 (3)
C6—C1—H1B	120.5	C9—C10—H10A	120.3
C1—C2—C3	121.0 (4)	C11—C10—H10A	120.3
C1—C2—H2B	119.5	C10—C11—C12	120.1 (3)
C3—C2—H2B	119.5	C10—C11—S	119.3 (3)
C2—C3—C4	120.1 (3)	C12—C11—S	120.6 (2)
C2—C3—H3A	119.9	C13—C12—C11	119.6 (3)
C4—C3—H3A	119.9	C13—C12—H12A	120.2
C3—C4—C5	118.6 (3)	C11—C12—H12A	120.2
C3—C4—N	122.3 (3)	C12—C13—C8	121.0 (3)
C5—C4—N	119.0 (3)	C12—C13—H13A	119.5
C6—C5—C4	120.2 (4)	C8—C13—H13A	119.5
C6—C5—H5A	119.9	S—C14—H14A	109.5
C4—C5—H5A	119.9	S—C14—H14B	109.5
C1—C6—C5	120.9 (4)	H14A—C14—H14B	109.5
C1—C6—H6A	119.6	S—C14—H14C	109.5
C5—C6—H6A	119.6	H14A—C14—H14C	109.5

N—C7—C8	123.2 (3)	H14B—C14—H14C	109.5
C6—C1—C2—C3	0.1 (6)	C8—C9—C10—C11	1.2 (6)
C1—C2—C3—C4	1.0 (6)	C9—C10—C11—C12	0.3 (6)
C2—C3—C4—C5	-1.0 (5)	C9—C10—C11—S	179.6 (3)
C2—C3—C4—N	175.0 (3)	O1—S—C11—C10	-144.6 (3)
C7—N—C4—C3	42.2 (5)	O2—S—C11—C10	-15.2 (3)
C7—N—C4—C5	-141.8 (3)	C14—S—C11—C10	100.2 (3)
C3—C4—C5—C6	0.0 (5)	O1—S—C11—C12	34.7 (3)
N—C4—C5—C6	-176.1 (3)	O2—S—C11—C12	164.1 (3)
C2—C1—C6—C5	-1.0 (6)	C14—S—C11—C12	-80.5 (3)
C4—C5—C6—C1	1.0 (6)	C10—C11—C12—C13	-1.3 (5)
C4—N—C7—C8	-177.2 (3)	S—C11—C12—C13	179.5 (3)
N—C7—C8—C9	-159.4 (4)	C11—C12—C13—C8	0.7 (6)
N—C7—C8—C13	18.9 (5)	C9—C8—C13—C12	0.7 (6)
C13—C8—C9—C10	-1.7 (6)	C7—C8—C13—C12	-177.6 (3)
C7—C8—C9—C10	176.6 (4)		

Fig. 1

